MT29F1G08ABBEAM68M3WC1

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Data Sheets (2)

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Orderable Parts (1)

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MT29F1G08ABBEAM68M3WC1

Orderable Part Information

Status	Production	**Alternative Part**	N/A
FBGA Code	N/A	**SPD Data**	N/A
MBQual Data	N/A	**Shipping Media**	N/A
PLP	No	**Start Date**	N/A

Specs

Density	1Gb	**Status**	Production
RoHS	Yes	**Width**	x8
Voltage	1.8V	**Package**	Wafer
Pin Count	n/a	**MT/s**	
I/O	Common		

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Date	What was added
10/2014	1Gb: x8, x16: NAND M68M
04/2014	IBIS: NAND 1Gb SLC (Rev E) M68M

FAQs

- Do you support small block devices?
- How much ECC do I need to support your devices?
- I am using the correct amount of error correction code (ECC) for the NAND device, but I'm still seeing bit/byte errors in data I read back from the NAND device.
- **See all FAQs**

Sim Models & Software

Title & Description	Secure	ID	Updated
HSpice: NAND 1Gb SLC (Rev E) M68M: Rev. 2.0		M68M	06/2012
IBIS: NAND 1Gb SLC (Rev E) M68M: Rev. 2.2		M68M	04/2014

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For MT29F1G08ABBEAM68M3WC1 (4)
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SLC NAND FAQs (3)

- Do you support small block devices?
- How much ECC do I need to support your devices?
- I am using the correct amount of error correction code (ECC) for the NAND device, but I'm still seeing bit/byte errors in data I read back from the NAND device.

NAND Flash FAQs (15)

- How do I achieve greater PROGRAM/READ throughput for the NAND device?
- How is Nvb specified?
- I am seeing a lot of READ DISTURB errors. Can you tell me if there is a problem with your part?
- I've heard that NAND has too many errors to boot from. Is this true?
- Should I be marking blocks bad due to READ errors?
- When I issue a Read ID command (90h) to a two-die NAND device, I get a device ID back that states it is a one-die NAND device.
- Where can I find additional technical information about Micron NAND devices that is not covered in the device data sheets?
- Where can I find simulation models for NAND Flash devices?
- Why am I getting a bit/byte error reading back the information I programmed into the NAND device?
- Why doesn't the NAND Flash device respond correctly to commands issued to it?
- What is a "bank"?
- What is the impedance tolerance of the driver in match-impedance mode relative to the expected value base on the perfect reference resistor connected to ZQ pin?
- Does thermal information change for IT parts?
- My design was based on a specification stating the JTAG was relative to VDD (1.8V), but now we've discovered that JTAG is actually relative to VDDQ (1.5V). It's a fairly significant board spin to change this; what do I risk by leaving the design as-is? I assume that the specification is still for VDDQ + 0.3V = 1.8V, but with CMOS parts there's no way I can guarantee that it won't swing past that on transitions.
- Should the ECC memory chip share chip select and CKE signals with the other two main memory chips in our point-to-point application?

Products and Support FAQs (1)

- Who do I contact if I have questions about my buymicron.com order?